NSN 5961-01-222-0253

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-222-0253 **Overall Length:** 0.354 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 3.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli

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